

# Quantum control of two qubits spin hole gates

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Hole spins in semiconductor quantum dots (QDs) are attracting significant attention as candidates for fast, highly coherent, spin qubits [1-4]. They have long coherence time due to the weak hyperfine coupling to nuclear spins and have demonstrated to have rapid operation times due to the inherently strong spin-orbit coupling (SOC).

In this work we investigate how to control a two-hole spin qubit consisting of a triplet and a singlet hole states. For that purpose, we implement a driving protocol based on Shortcuts to Adiabaticity (STA), minimizing noise effects while enhancing robustness [5, 6]. We consider the fast quasi-adiabatic (FAQUAD) approach and analyze its feasibility to manipulate hole spin qubits and compare with other alternative protocols. We can initialize the qubit in an arbitrary state and perform a NOT gate by changing the detuning between dots. In addition, we achieve a SWAP-like two-qubits gate with a fidelity beyond error correction threshold. We study the robustness of the protocol regarding systematic errors in the detuning, as well as charge noise [7].

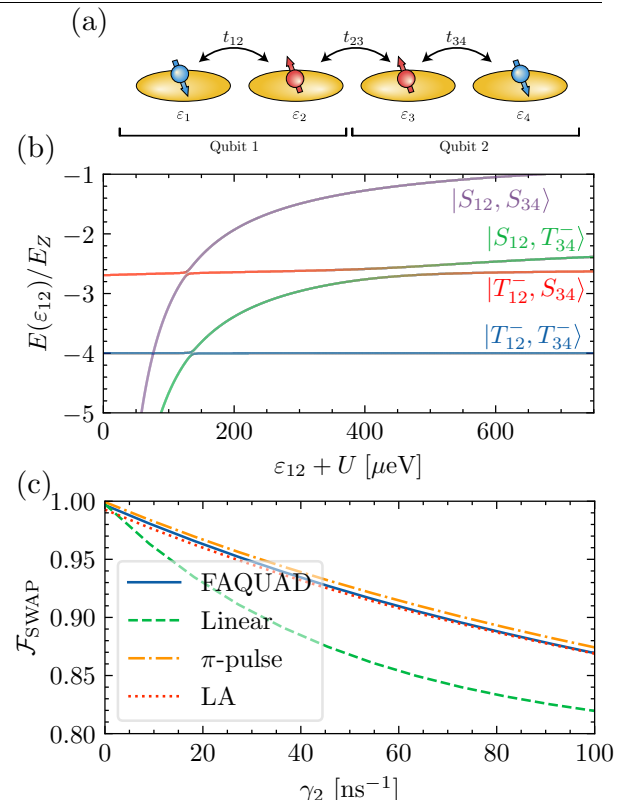
Furthermore, we study the direct transfer of entangled holes in QD arrays between edge sites by using inverse engineering techniques. We demonstrate that spin-conserving and spin-flipping direct transfer

between edges can be achieved in a controlled way with all-electrical protocols by dynamically tuning the tunnelling rates between dots [8].

## References

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## Figures



**Figure 1:** (a) Schematic picture of a quadruple quantum dot encoding two S-T qubits. (b) Energy level diagram of the system. (c) Fidelity of a SWAP gate against charge noise for different protocols.